

INCHANGE SEMICONDUCTOR

isc Silicon PNP Power Transistors

TIP42A

DESCRIPTION

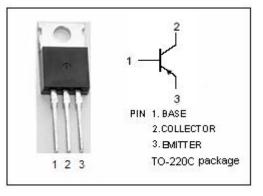
- DC Current Gain -hFE = 30(Min)@ IC= -0.3A
- Collector-Emitter Sustaining Voltage- $: V_{CEO(SUS)} = -60V(Min)$
- Complement to Type TIP41A
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

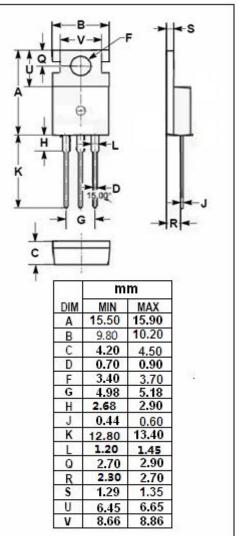
APPLICATIONS

· Designed for use in general purpose amplifer and switching applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)									
SYMBOL	PARAMETER		ALUE	UNIT					
V _{CBO}	Collector-Base Voltage		-60	V					
V _{CEO}	Collector-Emitter Voltage		-60	V					
V_{EBO}	Emitter-Base Voltage		-5	V					
Ic	Collector Current-Continuous		-6	A					
I _{CM}	Collector Current-Peak		-10	А					
I _B	Base Current	-2		А					
Pc	Collector Power Dissipation $T_c=25^{\circ}C$	65 2		W					
	Collector Power Dissipation $T_a=25^\circ\mathbb{C}$								
Tj	Junction Temperature	150		°C					
T _{stg}	Storage Temperature Range	-65~150		°C					
THERMAL CHARACTERISTICS									
SYMBOL	PARAMETER		MAX	UNIT					
R _{th j-c}	Thermal Resistance, Junction to Case			°C/W					
R _{th j-a}	Thermal Resistance, Junction to Ambient			°C/W					

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -30mA; I _B = 0	-60		V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -6A; I _B = -0.6A		-1.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -6A; V _{CE} = -4V		-2.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -60V; I _E = 0		-0.4	mA
I _{CEO}	Collector Cutoff Current	V _{CE} = -30V; I _B = 0		-0.7	mA
І _{ЕВО}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0		-1.0	mA
h _{FE-1}	DC Current Gain	I _C = -0.3A ; V _{CE} = -4V	30		
h _{FE-2}	DC Current Gain	I _C = -3A ; V _{CE} = -4V	15	75	
f⊤	Current-Gain—Bandwidth Product	I _C = -0.5A; V _{CE} = -10V	3		MHz

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